

SOT-23 Plastic-Encapsulate Diodes

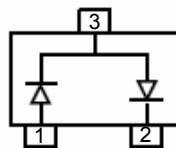
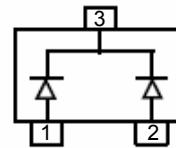
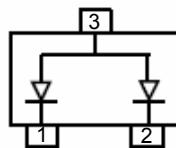
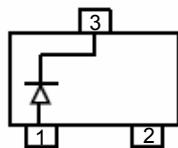
MMBD4148A/SE/CC/CA SWITCHING DIODES

FEATURES

Power Dissipation

PD : 350 mW (Tamb=25°C)

SOT-23



MARKING:

MMBD4148A:5H

MMBD4148CA:D6

MMBD4148CC:D5

MBD4148SE:D4

Maximum Ratings @TA=25

Parameter	Symbol	Limits			Unit
Peak Repetitive Peak reverse voltage	V _{RRM}				
Working Peak Reverse Voltage	V _{RWM}	100			V
DC Blocking Voltage	V _R				
Forward Continuous Current	I _{FM}	200			mA
Power Dissipation	Pd	350			mW
Storage temperature	T _{STG}	-55-150			°C

Electrical Characteristics@TA=25°C

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Reverse Breakdown Voltage	V _{(BR)R1}	100			V	IR=100μA
	V _{(BR)R2}	75			V	IR=5μA
Forward voltage	V _F			1	V	I _F =10mA
Reverse current	I _{R1}			25	nA	V _R =25V
	I _{R2}			5	uA	V _R =75V
Diode Capacitance	C _D			4	pF	V _R =0V,f=1MHz
Reverse Recovery Time	t _{rr}			4	nS	I _F =10mA,V _R =6V I _{rr} =0.1XI _R ,R _L =100Ω

Typical Characteristics

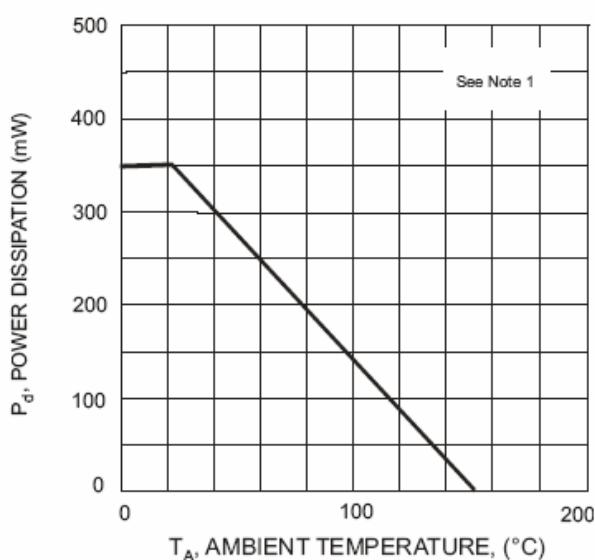


Fig. 1 Power Derating Curve

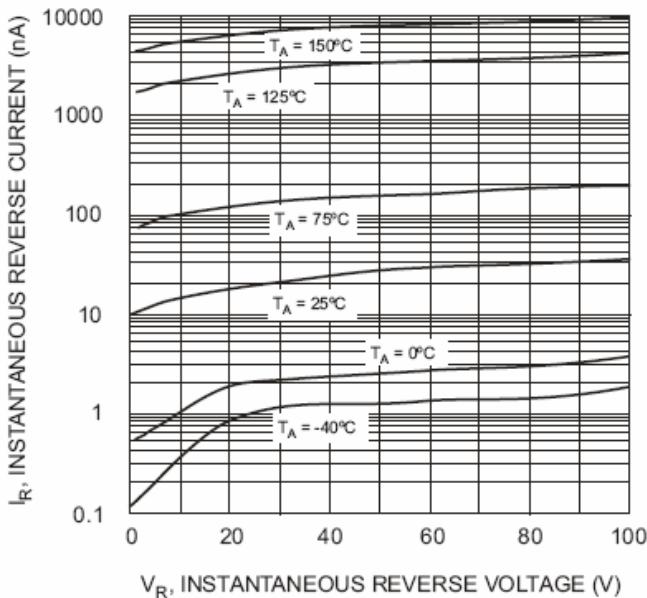


Fig. 3 Typical Reverse Characteristics

MMBD4148A/SE/CC/CA

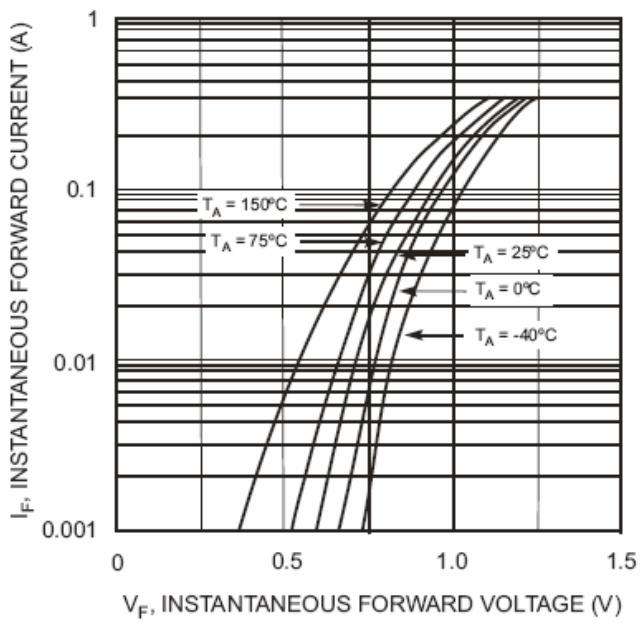


Fig. 2 Forward Characteristics

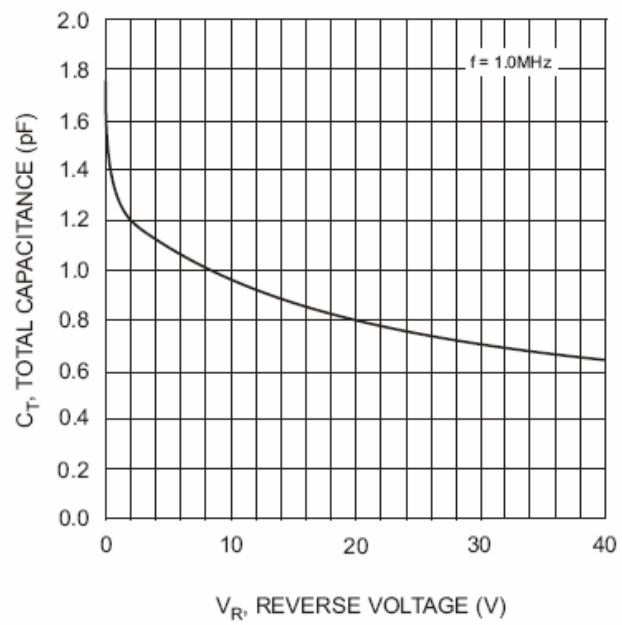


Fig. 4 Typical Capacitance vs. Reverse Voltage